"FOD8012"

FAIRCHILD

SEMICONDUCTOR®

November 2010

FOD8012
High CMR, Bi-Directional, Logic Gate Optocoupler

Features

- Full Duplex, Bi-Directional
- 20kV/µs Minimum Common Mode Rejection
- High Speed:
  - 15Mbit/sec Data Rate (NRZ)
  - 60ns max. Propagation Delay
  - 15ns max. Pulse Width Distortion
  - 30ns max. Propagation Delay Skew
- 3.3V and 5V CMOS Compatibility
- Extended industrial temperate range, -40 to +110˚C temperature range
- Safety and regulatory approvals
  - UL1577, 3750 VAC$_{RMS}$ for 1 min.
  - DIN EN/IEC60747-5-2 (approval pending)

Applications

- Industrial fieldbus communications
  - DeviceNet, CAN, RS485, RS232
- Microprocessor System Interface
  - SPI, I^{2}C
- Programmable Logic Control
- Isolated Data Acquisition System
- Voltage Level Translator

Description

The FOD8012 is a full duplex, bi-directional, high-speed logic gate Optocoupler, which supports isolated communications allowing digital signals to communicate between systems without conducting ground loops or hazardous voltages. It utilizes Fairchild's patented coplanar packaging technology, Optoplanar®, and optimized IC design to achieve minimum 20kV/µs Common Mode Noise Rejection (CMR) rating.

This high-speed logic gate optocoupler is highly integrated with 2 optically coupled channels arranged in bi-directional configuration, and housed in a compact 8-pin small outline package. Each optocoupler channel consists of a high-speed AlGaAs LED driven by a CMOS buffer IC coupled to a CMOS detector IC. The detector IC comprises of an integrated photodiode, a high-speed trans-impedance amplifier and a voltage comparator with an output driver. The CMOS technology coupled to the high efficiency of the LED achieves low power consumption as well as very high speed (60ns propagation delay, 15ns pulse width distortion).

Related Resources

- FOD8001, High Noise Immunity, 3.3V/5V Logic Gate Optocoupler Datasheet
- www.fairchildsemi.com/products/opto/

Functional Schematic

0.1µF bypass capacitor required from V$_{DD}$ to GND
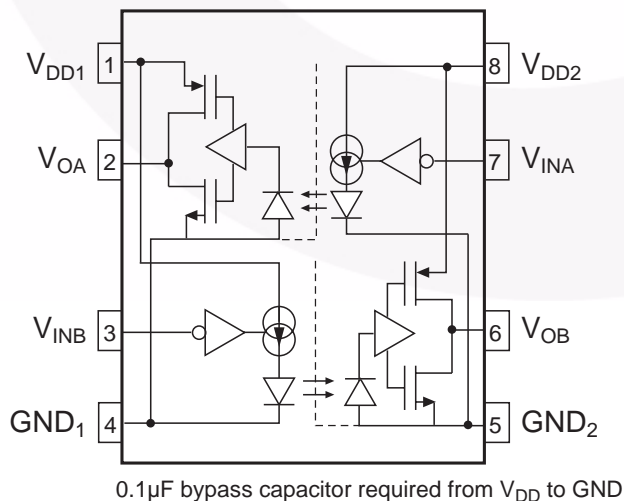
Truth Table

VIN	LED	VO
High	OFF	High
Low	ON	Low

"FOD8012"
Pin Definitions

Pin Number	Pin Name	Description
1	V_{DD1}	**Supply Voltage** to Channel-A detector IC and Channel-B buffer IC
2	V_{OA}	**Output Voltage** from Channel-A detector IC
3	V_{INB}	**Input Voltage** to Channel-B buffer IC
4	GND_1	**Ground** for Channel-A detector IC and Channel-B buffer IC
5	GND_2	**Ground** for Channel-A buffer IC and Channel-B detector IC
6	V_{OB}	**Output Voltage** from Channel-B detector IC
7	V_{INA}	**Input Voltage** to Channel-A buffer IC
8	V_{DD2}	**Supply Voltage** to Channel-A buffer IC and Channel-B detector IC

Absolute Maximum Ratings (T_A=25ºC unless otherwise specified)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Value	Units
T_{STG}	Storage Temperature	-40 to +125	ºC
T_{OPR}	Operating Temperature	-40 to +110	ºC
T_J	Junction Temperature	-40 to +130	ºC
T_{SOL}	Lead Solder Temperature (Refer to Reflow Temperature Profile)	260 for 10sec	ºC
V_{DD1}, V_{DD2}	Supply Voltage	0 to 6.0	V
V_{IA}, V_{IB}	Input Voltage	-0.5 to VDD+0.5	V
I_{IA}, I_{IB}	Input DC Current	-10 to +10	µA
V_{OA}, V_{OB}	Output Voltage	-0.5 to VDD+0.5	V
I_{OA}, I_{OB}	Average Output Current	10	mA
PD_I	Input Power Dissipation[1]	60	mW
PD_O	Output Power Dissipation[1]	60	mW

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
T_A	Ambient Operating Temperature	-40	+110	ºC
V_{DD1}, V_{DD2}	Supply Voltages (3.3V Operation)[2]	3.0	3.6	V
	Supply Voltages (5.0V Operation)[2]	4.5	5.5	V
V_{IH}	Logic High Input Voltage	2.0	V_{DD}	V
V_{IL}	Logic Low Input Voltage	0	0.8	V
t_r, t_f	Input Signal Rise and Fall Time		1.0	ms

Isolation Characteristics

Apply over all recommended conditions, typical value is measured at T_A = 25ºC

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
V_{ISO}	Input-Output Isolation Voltage	freq = 60Hz, t = 1.0min, $I_{I-O} \leq 10\mu A^{(3)(4)}$	3750			Vac$_{RMS}$
R_{ISO}	Isolation Resistance	V_{I-O} = 500V$^{(3)}$	10^{11}			Ω
C_{ISO}	Isolation Capacitance	V_{I-O} = 0V, freq = 1.0MHz$^{(3)}$		0.2		pF

Electrical Characteristics

T_A = -40ºC to +110ºC, 3.0V $\leq V_{DD} \leq$ 5.5V, unless otherwise specified.
Apply over all recommended conditions, typical value is measured at $V_{DD1} = V_{DD2}$ = +3.3V, T_A = 25ºC

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
I_{DD1L}, I_{DD2L}	Logic Low Supply Current	V_{IA}, V_{IB} = 0V		5.8	8.0	mA
I_{DD1H}, I_{DD2H}	Logic High Supply Current	V_{IA}, $V_{IB} = V_{DD}$		2.5	4.0	mA
I_{IA}, I_{IB}	Input Current		-10		+10	µA
V_{OH}	Logic High Output Voltage	I_O = −20µA, V$_{DD}$ = 3.3V, $V_I = V_{IH}$	3.2	3.3		V
		I_O = −4mA, V$_{DD}$ = 3.3V, $V_I = V_{IH}$	3.0	3.1		V
		I_O = −20µA, V$_{DD}$ = 5V, $V_I = V_{IH}$	4.9	5.0		V
		I_O = −4mA, V$_{DD}$ = 5V, $V_I = V_{IH}$	4.7	4.8		V
V_{OL}	Logic Low Output Voltage	I_O = 20µA, V$_{DD}$ = 3.3V or 5V, $V_I = V_{IL}$		0	0.1	V
		I_O = 4mA, V$_{DD}$ = 3.3V or 5V, $V_I = V_{IL}$		0.26	0.6	V

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Switching Characteristics

T_A = -40ºC to +110ºC, 3.0V $\leq V_{DD} \leq$ 5.5V, unless otherwise specified.
Apply over all recommended conditions, typical value is measured at V_{DD1} = V_{DD2} = +3.3V, T_A=25ºC

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Units
Data Rate					15	Mbit/s
t_{PHL}	Propagation Delay Time to Logic Low Output	PW = 66.7ns, C_L = 15pF		37	60	ns
t_{PLH}	Propagation Delay Time to Logic High Output	PW = 66.7ns, C_L = 15pF		40	60	ns
PWD	Pulse Width Distortion, $\lvert t_{PHL} - t_{PLH} \rvert$	PW = 66.7ns, C_L = 15pF[5]		3	15	ns
$t_{PSK(CC)}$	Channel-Channel Skew	PW = 66.7ns, C_L = 15pF[6]		12	25	ns
$t_{PSK(PP)}$	Part-Part Skew	PW = 66.7ns, C_L = 15pF[7]			30	ns
t_R	Output Rise Time (10% to 90%)	PW = 66.7ns, C_L = 15pF		6.5		ns
t_F	Output Fall Time (90% to 10%)	PW = 66.7ns, C_L = 15pF		6.5		ns
$\lvert CM_H \rvert$	Common Mode Transient Immunity at Output High	V_I = V_{DD1}, V_O > $0.8V_{DD1}$, V_{CM} = 1000V[8]	20	40		kV/µs
$\lvert CM_L \rvert$	Common Mode Transient Immunity at Output Low	V_I = 0V, V_O < 0.8V, V_{CM} = 1000V[8]	20	40		kV/µs

Notes:

1. No derating required.

2. 0.1µF bypass capacitor must be connected between Pin 1 and 4, and 5 and 8. The capacitors should be kept close to the supply pins.

3. Device is considered a two terminal device: Pins 1, 2, 3 and 4 are shorted together and Pins 5, 6, 7 and 8 are shorted together.

4. 3,750 VAC_{RMS} for 1 minute duration is equivalent to 4,500 VAC_{RMS} for 1 second duration.

5. PWD is equal to the magnitude of the worst case difference in t_{PHL} and/or t_{PLH} that will be seen for one channel switching, while holding the other channel output at a low or high state, or while both channels are in synchronous data transmission mode.

6. $t_{PSK(CC)}$ is equal to the magnitude of the worst case difference in t_{PHL} and/or t_{PLH} that will be seen between the two channels within a single device.

7. $t_{PSK(PP)}$ is equal to the magnitude of the worst case difference in t_{PHL} and/or t_{PLH} that will be seen between any two units from the same manufacturing date code that are operated at same case temperature, at same operating conditions, with equal loads.

8. Common mode transient immunity at output high is the maximum tolerable positive dVcm/dt on the leading edge of the common mode impulse signal, Vcm, to assure that the output will remain high. Common mode transient immunity at output low is the maximum tolerable negative dVcm/dt on the trailing edge of the common pulse signal, Vcm, to assure that the output will remain low.

Typical Performance Curves

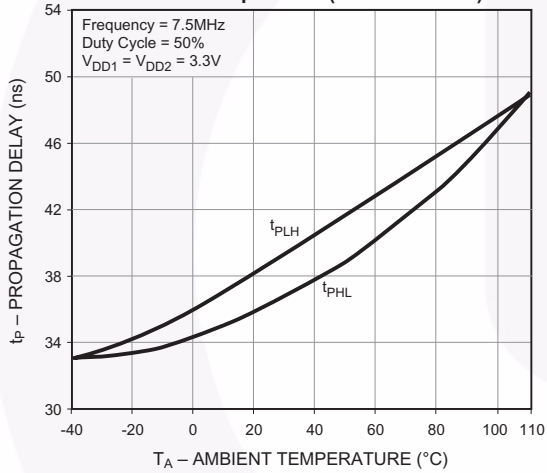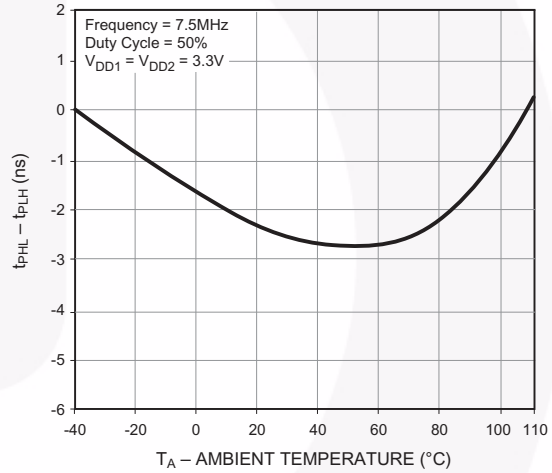**Fig. 1 Typical Output Voltage vs. Input Voltage (Channel A & B)**

$V_{DD1} = V_{DD1} = 3.3V$

X-axis: V_I – INPUT VOLTAGE (V)
Y-axis: V_O – OUTPUT VOLTAGE (V)
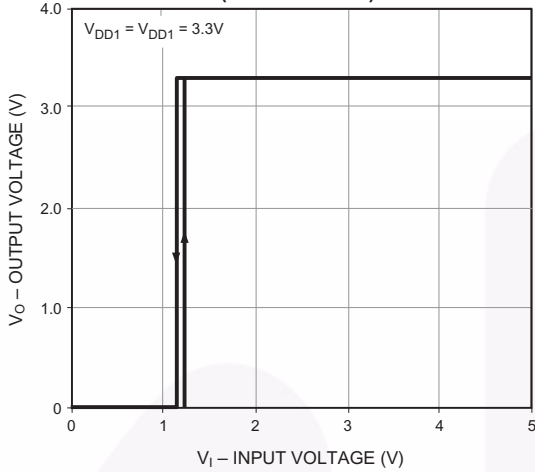
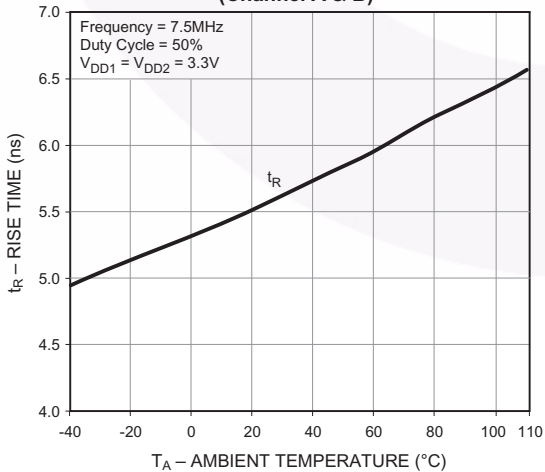**Fig. 2 Typical Input Voltage Switching Threshold vs. Input Supply Voltage (Channel A & B)**

X-axis: V_{DD} – SUPPLY VOLTAGE (V)
Y-axis: V_{ITH} – INPUT VOLTAGE SWITCHING THRESHOLD (V)
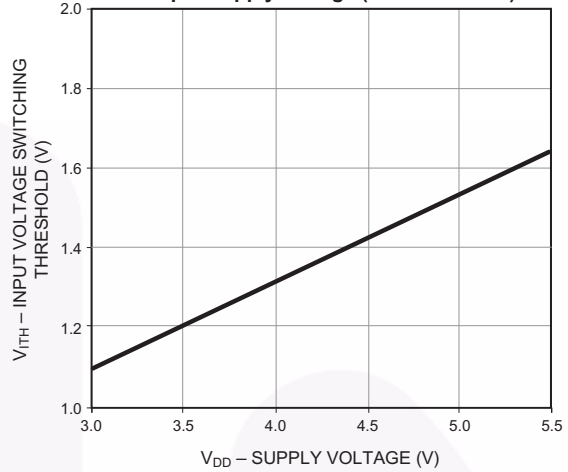
Fig. 3 Typical Propagation Delay vs. Ambient Temperature (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_{PLH}
t_{PHL}

X-axis: T_A – AMBIENT TEMPERATURE (°C)
Y-axis: t_P – PROPAGATION DELAY (ns)

Fig. 4 Typical t_{PHL} – t_{PLH} vs. Ambient Temperature (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

X-axis: T_A – AMBIENT TEMPERATURE (°C)
Y-axis: t_{PHL} – t_{PLH} (ns)

Fig. 5 Typical Rise Time vs. Ambient Temperature (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_R

X-axis: T_A – AMBIENT TEMPERATURE (°C)
Y-axis: t_R – RISE TIME (ns)

Fig. 6 Typical Fall Time vs. Ambient Temperature (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_F

X-axis: T_A – AMBIENT TEMPERATURE (°C)
Y-axis: t_F – FALL TIME (ns)
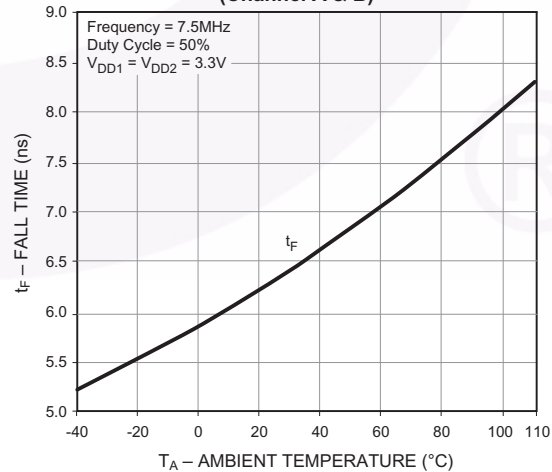
Typical Performance Curves (Continued)

Fig. 7 Typical Propagation Delay vs. Output Load Capacitance (Channel A & B)

Frequency = 7.5MHz
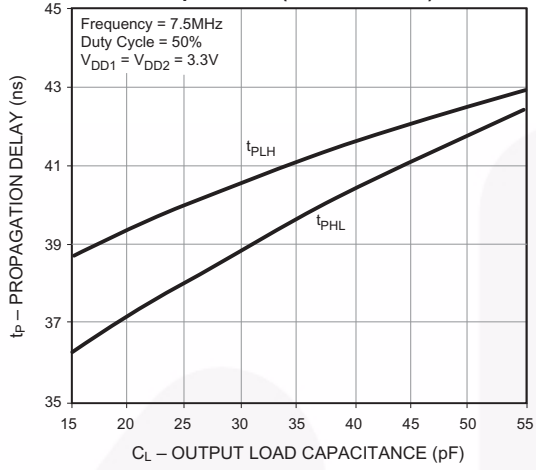Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_{PLH}
t_{PHL}

t_P – PROPAGATION DELAY (ns)
C_L – OUTPUT LOAD CAPACITANCE (pF)

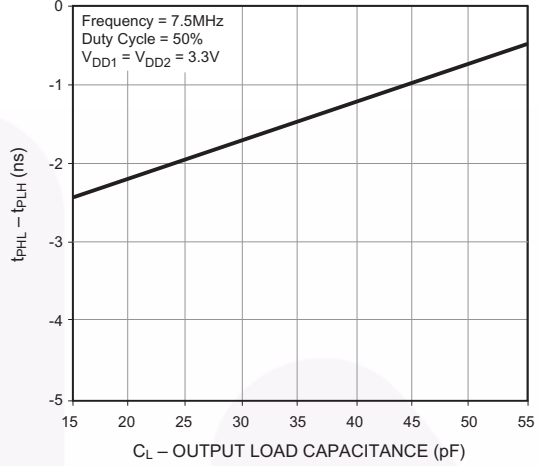**Fig. 8 Typical t_{PHL} – t_{PLH} vs. Output Load Capacitance (Channel A & B)**

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_{PHL} – t_{PLH} (ns)
C_L – OUTPUT LOAD CAPACITANCE (pF)

Fig. 9 Typical Rise Time vs. Output Load Capacitance (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_R

t_R – RISE TIME (ns)
C_L – OUTPUT LOAD CAPACITANCE (pF)
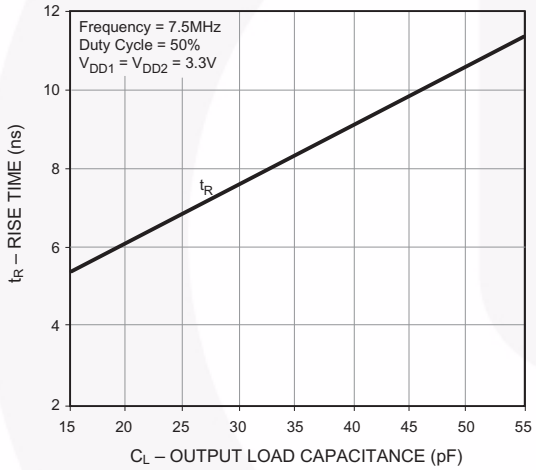
Fig. 10 Typical Fall Time vs. Output Load Capacitance (Channel A & B)

Frequency = 7.5MHz
Duty Cycle = 50%
$V_{DD1} = V_{DD2} = 3.3V$

t_F

t_F – FALL TIME (ns)
C_L – OUTPUT LOAD CAPACITANCE (pF)

"FOD8012"
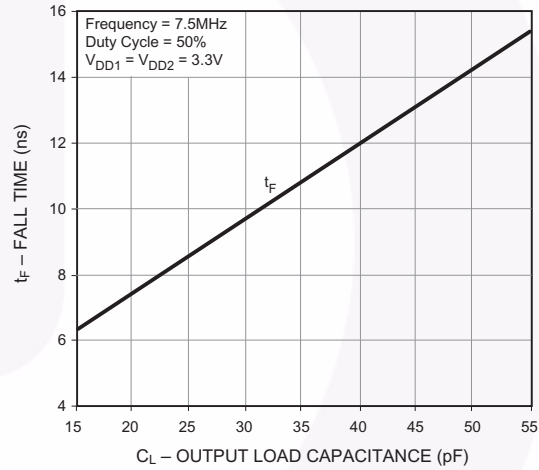
Typical Performance Curves (Continued)

Fig. 11a Typical I$_{DD1}$/I$_{DD2}$ Supply Current vs. Frequency

V$_{DD1}$ = V$_{DD2}$ = 5.5V, T$_A$ = 25°C
V$_{INA}$ and V$_{INB}$ Switching
Pin 2 and 6 Floating

T$_A$ = -40°C
T$_A$ = 25°C
T$_A$ = 110°C
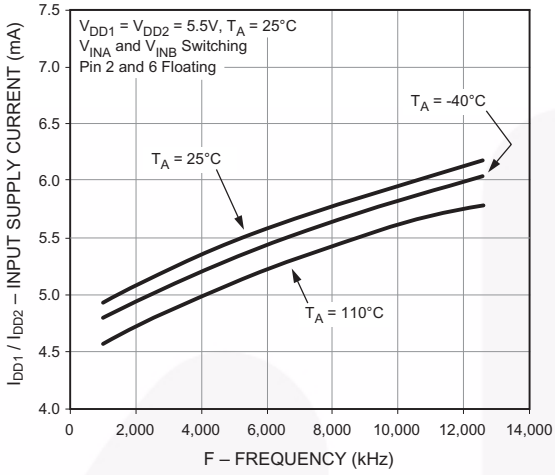
Fig. 11b Typical I$_{DD1}$/I$_{DD2}$ Supply Current vs. Frequency

V$_{DD1}$ = V$_{DD2}$ = 5.5V, T$_A$ = 25°C
V$_{INB}$ = 0V @ I$_{DD1}$, V$_{INA}$ Switching
V$_{INA}$ = 0V @ I$_{DD2}$, V$_{INB}$ Switching
Pin 2 and 6 Floating

T$_A$ = 25°C
T$_A$ = 110°C
T$_A$ = -40°C
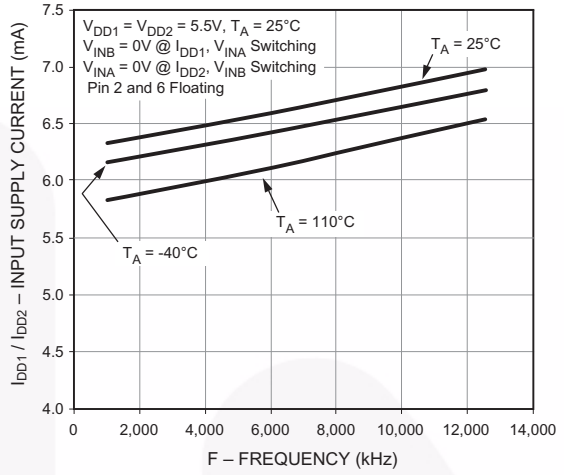
Fig. 11c Typical I$_{DD1}$/I$_{DD2}$ Supply Current vs. Frequency

V$_{DD1}$ = V$_{DD2}$ = 5.5V, T$_A$ = 25°C
V$_{INA}$ = 0V @ I$_{DD1}$, V$_{INB}$ Switching
V$_{INB}$ = 0V @ I$_{DD2}$, V$_{INA}$ Switching
Pin 2 and 6 Floating

T$_A$ = -40°C
T$_A$ = 25°C
T$_A$ = 110°C
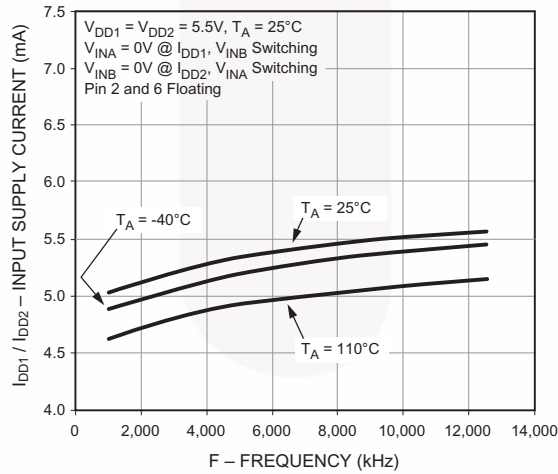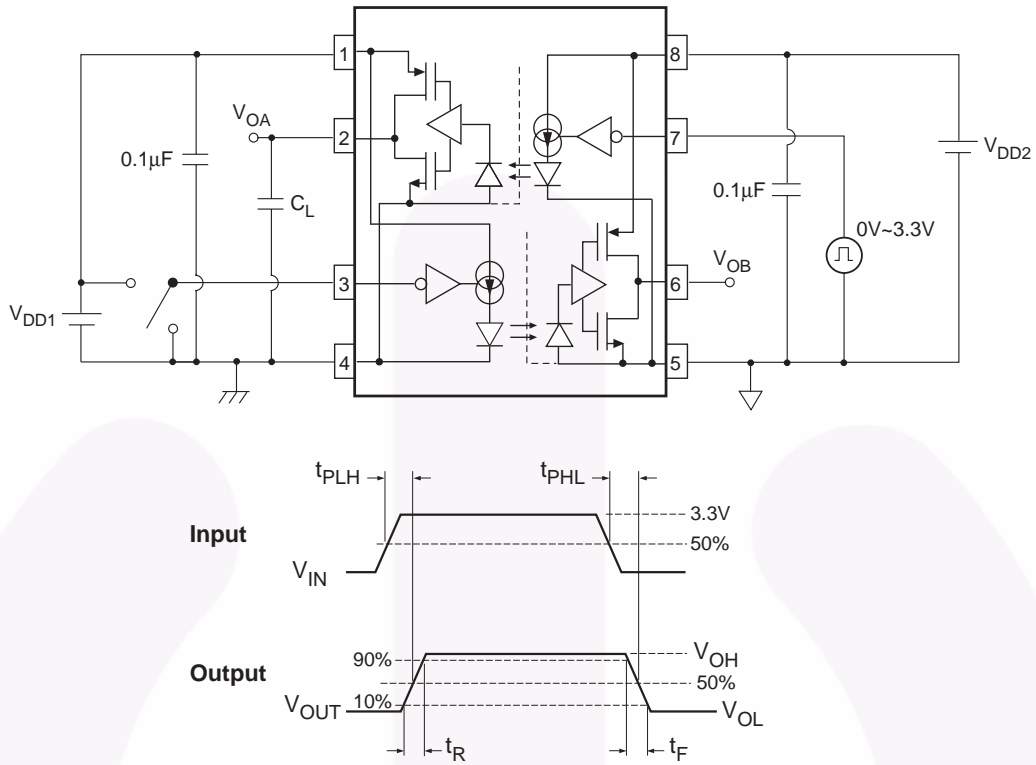
Test Circuits

Figure 11. Test Circuit for Propogation Delay Time and Rise Time, Fall Time
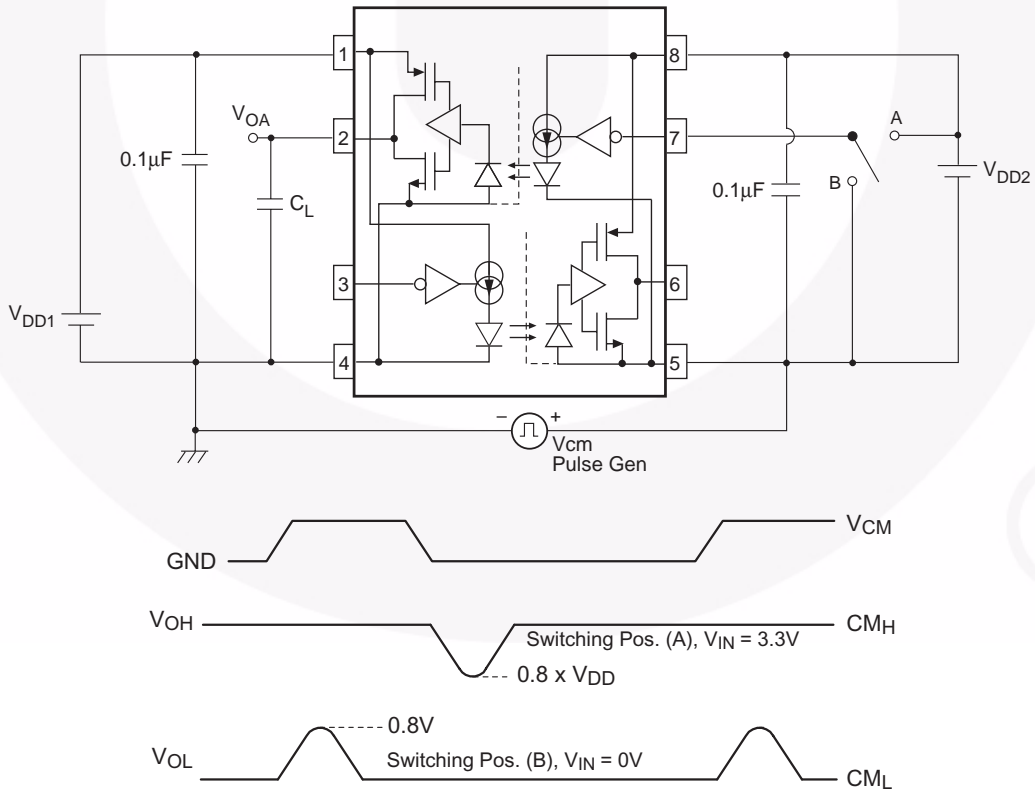
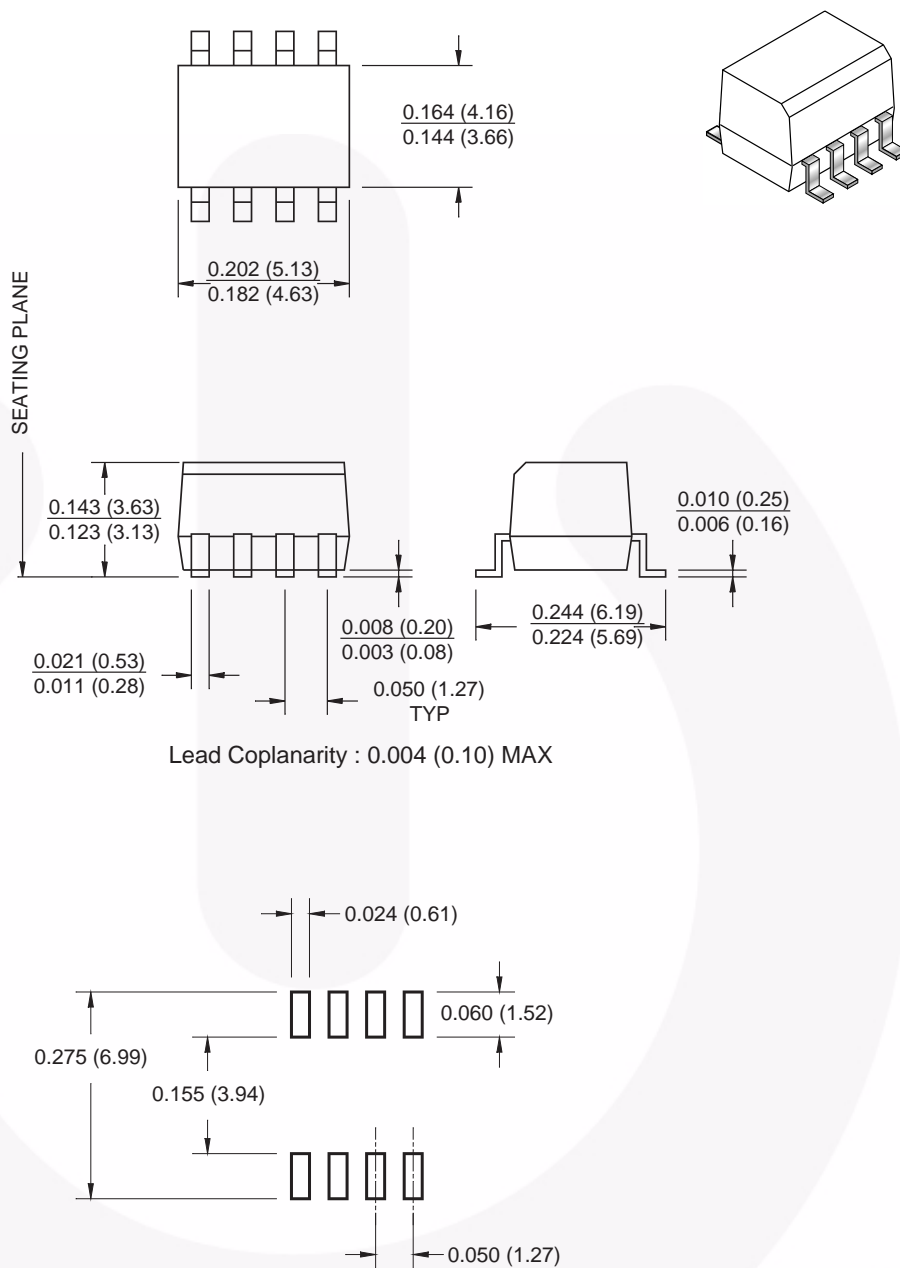**Figure 12. Test Circuit for Instantaneous Common Mode Rejection Voltage**

"FOD8012"
Small Outline Package Dimensions

0.164 (4.16)
0.144 (3.66)

0.202 (5.13)
0.182 (4.63)

SEATING PLANE

0.143 (3.63)
0.123 (3.13)

0.010 (0.25)
0.006 (0.16)

0.021 (0.53)
0.011 (0.28)

0.008 (0.20)
0.003 (0.08)

0.244 (6.19)
0.224 (5.69)

0.050 (1.27)
TYP

Lead Coplanarity : 0.004 (0.10) MAX

0.024 (0.61)

0.060 (1.52)

0.275 (6.99)

0.155 (3.94)

0.050 (1.27)

Note:
All dimensions are in millimeters.

Package drawings are provided as a service to customers considering Fairchild components. Drawings may change in any manner without notice. Please note the revision and/or date on the drawing and contact a Fairchild Semiconductor representative to verify or obtain the most recent revision. Package specifications do not expand the terms of Fairchild's worldwide terms and conditions, specifically the warranty therein, which covers Fairchild products.

Always visit Fairchild Semiconductor's online packaging area for the most recent package drawings:
http://www.fairchildsemi.com/packaging/

"FOD8012"
Carrier Tape Specification

8.0 ± 0.10
2.0 ± 0.05
Ø1.5 MIN
3.50 ± 0.20
0.30 MAX
4.0 ± 0.10
1.75 ± 0.10
8.3 ± 0.10
5.5 ± 0.05
12.0 ± 0.3
5.20 ± 0.20
0.1 MAX
6.40 ± 0.20
Ø1.5 ± 0.1/-0

User Direction of Feed
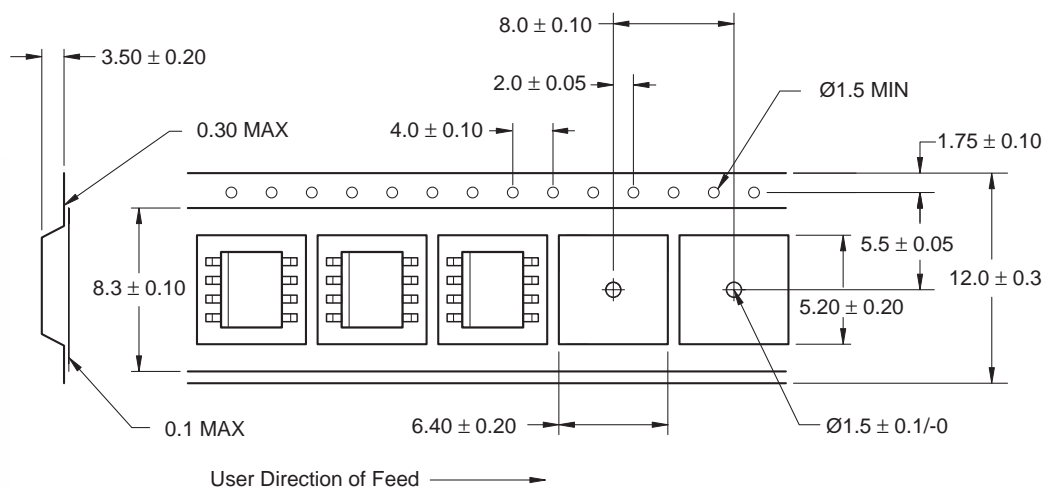
Note:
All dimensions are in millimeters.

Ordering Information

Option	Order Entry Identifier	Description
No Suffix	FOD8012	Small outline 8-pin, shipped in tubes (50 units per tube)
R2	FOD8012R2	Small outline 8-pin, tape and reel (2,500 units per reel)

All packages are lead free per JEDEC: J-STD-020B standard.

Marking Information
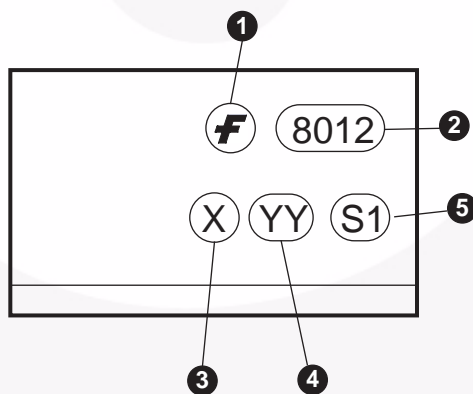
Definitions	
1	Fairchild logo
2	Device number
3	One digit year code, e.g., '8'
4	Two digit work week ranging from '01' to '53'
5	Assembly package code

Reflow Profile

Max. Ramp-up Rate = 3°C/S
Max. Ramp-down Rate = 6°C/S
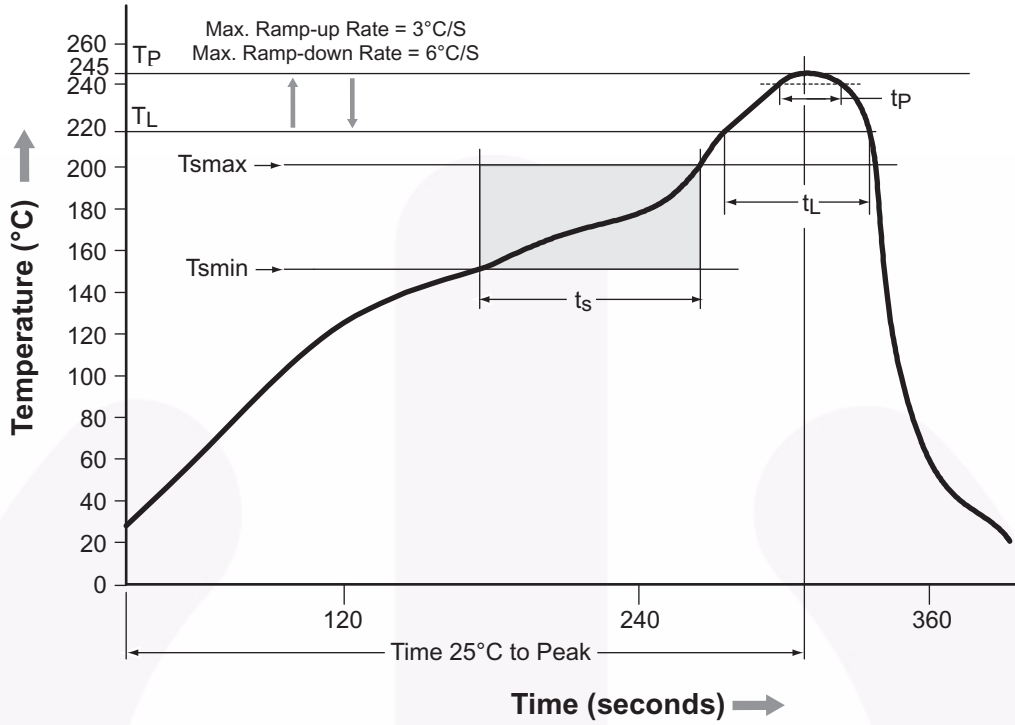
Profile Freature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (t_S) from (Tsmin to Tsmax)	60–120 seconds
Ramp-up Rate (t_L to t_P)	3°C/second max.
Liquidous Temperature (T_L)	217°C
Time (t_L) Maintained Above (T_L)	60–150 seconds
Peak Body Package Temperature	245°C +0°C / –5°C
Time (t_P) within 5°C of 245°C	30 seconds
Ramp-down Rate (T_P to T_L)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.

"FOD8012"

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ESBC™
F®
Fairchild®
Fairchild Semiconductor®
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FACT®
FAST®
FastvCore™
FETBench™
FlashWriter®*
FPS™

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Green FPS™ e-Series™
Gmax™
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ISOPLANAR™
MegaBuck™
MICROCOUPLER™
MicroFET™
MicroPak™
MicroPak2™
MillerDrive™
MotionMax™
Motion-SPM™
OptoHiT™
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®
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PowerTrench®
PowerXS™
Programmable Active Droop™
QFET®
QS™
Quiet Series™
RapidConfigure™
™
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SMART START™
SPM®
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SuperFET™
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SupreMOS®
SyncFET™
Sync-Lock™

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the
power™
franchise
TinyBoost™
TinyBuck™
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TinyPower™
TinyPWM™
TinyWire™
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ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

Rev. I49